

Features

1. Ac inputs.
2. Opaque type, mini-flat package.
3. Subminiature type (The volume is smaller than that of our conventional DIP type by as far as 30%)
4. Isolation voltage between input and output (Viso:3750Vrms).

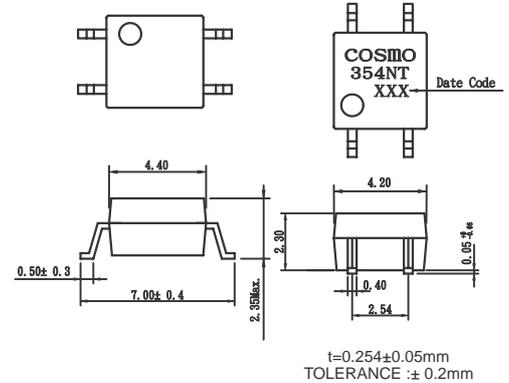
Applications

1. Hybrid substrates that require high density mounting.
2. Programmable controllers.

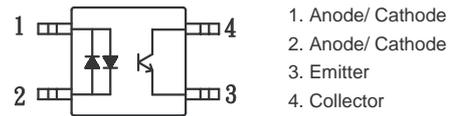
Classification table of current transfer ratio is shown below.

| RANK MARK | CTR(%) |
|-----------|-----------|
| A | 50 TO 150 |
| B | 20 TO 400 |

Outside Dimension : Unit (mm)



Schematic : Top View



Absolute Maximum Ratings

(Ta=25°C)

| Parameter | | Symbol | Rating | Unit |
|---------------------------------|-----------------------------|--------|-------------|------|
| Input | Forward current | IF | ± 50 | mA |
| | Peak forward current | IFM | ± 1 | A |
| | Power dissipation | P | 70 | mW |
| Output | Collector-emitter voltage | VCEO | 60 | V |
| | Emitter-collector voltage | VECO | 5 | V |
| | Collector current | IC | 50 | mA |
| | Collector power dissipation | PC | 150 | mW |
| Total power dissipation | | Ptot | 170 | mW |
| Isolation voltage 1 minute | | Viso | 3750 | Vrms |
| Operating temperature | | Topr | -30 to +100 | °C |
| Storage temperature | | Tstg | -40 to +125 | °C |
| Soldering temperature 10 second | | Tsol | 260 | °C |

Electro-optical Characteristics

(Ta=25°C)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|--------------------------|--------------------------------------|-----------|---------------------------------|--------------------|------------------|------|------|
| Input | Forward voltage | VF | IF = ± 20mA | — | 1.2 | 1.4 | V |
| | Terminal capacitance | Ct | V = 0, f = 1kHz | — | 30 | 250 | pF |
| Output | Collector dark current | ICEO | VCE = 20V, IF = 0 | — | — | 0.1 | uA |
| | Collector-emitter breakdown voltage | BVCEO | IC = 0.1mA, IF = 0 | 60 | — | — | V |
| | Emitter-collector breakdown voltage | BVECO | IE = 100uA, IF = 0 | 5 | — | — | V |
| Transfer characteristics | Current transfer ratio | CTR | IF = ± 1mA, VCE = 5V | 20 | — | 400 | % |
| | Collector-emitter saturation voltage | VCE (sat) | IF = ± 20mA, IC = 1mA | — | 0.1 | 0.3 | V |
| | Isolation resistance | Riso | DC500V, 40 to 60%RH | 5X10 ¹⁰ | 10 ¹¹ | — | ohm |
| | Floating capacitance | Cf | V = 0, f = 1MHz | — | 0.6 | 1.0 | pF |
| | Response time (Rise) | tr | VCE = 2V, IC = 2mA, RL = 100ohm | — | 4 | 18 | us |
| | Response time (Fall) | tf | | — | 3 | 18 | us |

Fig.1 Forward Current vs. Ambient Temperature

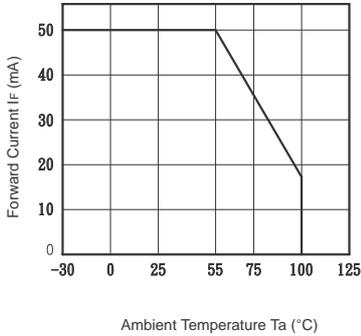


Fig.2 Diode Power Dissipation vs. Ambient Temperature

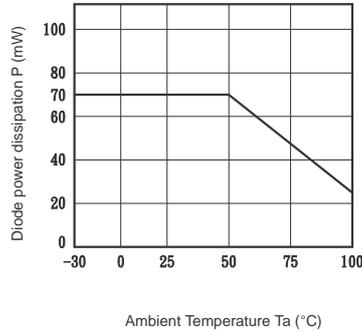


Fig.3 Collector Power Dissipation vs. Ambient Temperature

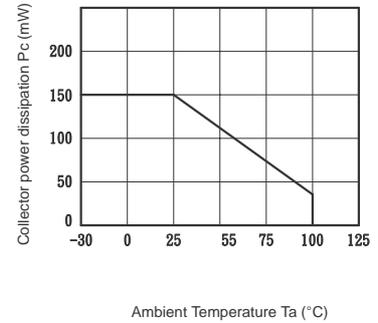


Fig.4 Total Power Dissipation vs. Ambient Temperature

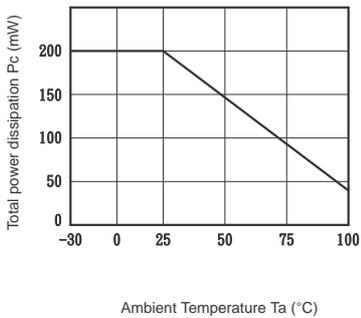


Fig.5 Peak Forward Current vs. Duty Ratio

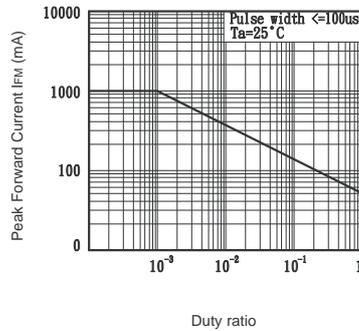


Fig.6 Forward Current vs. Forward Voltage

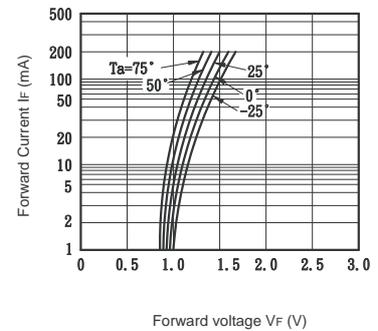


Fig.7 Current Transfer Ratio vs. Forward Current

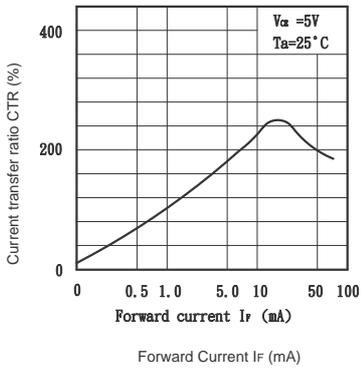


Fig.8 Collector Current vs. Collector-emitter Voltage

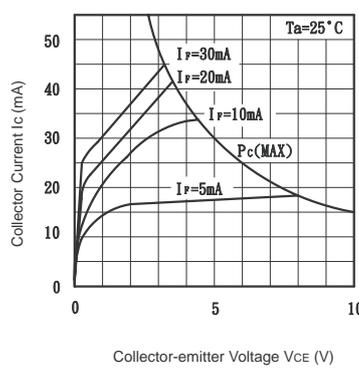


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

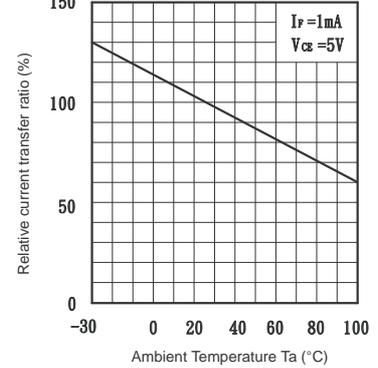


Fig.10 Collector-emitter Saturation Voltage vs. Ambient Temperature

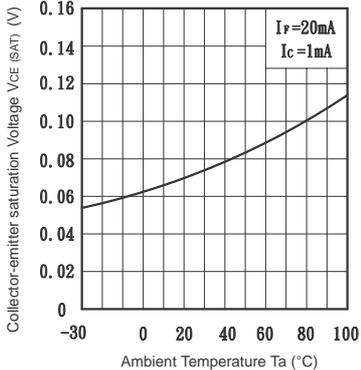


Fig.11 Collector Dark Current vs. Ambient Temperature

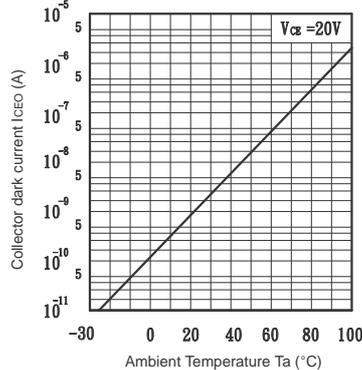


Fig.12 Response Time vs. Load Resistance

